

AN6387

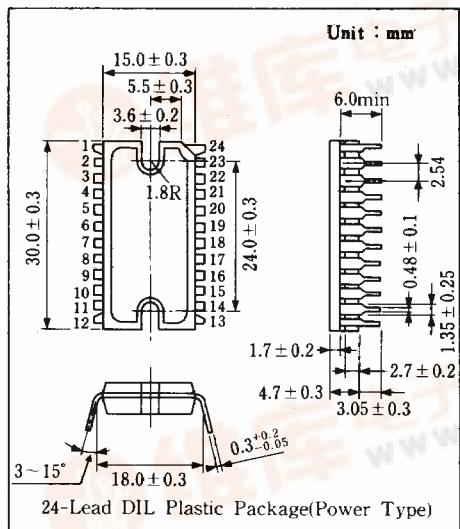
VCR Cylinder Direct Motor Drive Circuit

■ Outline

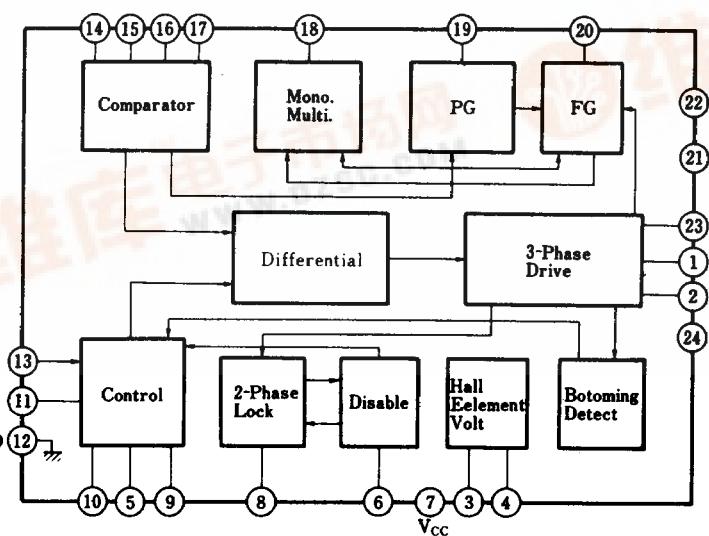
The AN6387 is an integrated circuit designed to drive a VCR cylinder DD motor.

■ Features

- The functions consist of :
 - 3-Phase motor drive circuit
 - 2-Phase Hall element input circuit
 - PG, FG, generator circuit
 - Motor lock detector
- Supply voltage : either 9V or 12V



■ Block Diagram



■ Pin

Pin No.	Pin Name		Pin No.	Pin Name	
1	Motor Current	(2)	13	Torque Direct Voltage	
2	Output	(3)	14		(1)
3	Hall Element Ref. Voltage		15	Hall Element	(2)
4	Hall Element Voltage		16	Voltage Input	(3)
5	Motor Current Detect		17		(4)
6	Disable		18	MM Output	
7	V _{CC}		19	PG Output	
8	Lock Detect		20	FG Output	
9	Phase Compensation		21	V _M	
10	Phase Compensation		22	NC	
11	Servo Ref. Voltage		23	Motor Current Output(1)	
12	GND		24	Motor Current	

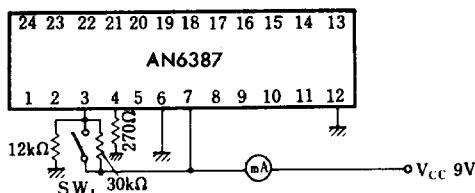
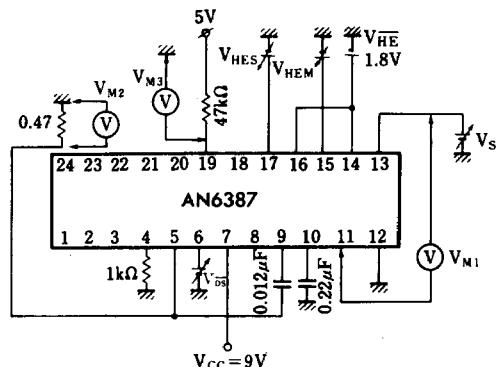
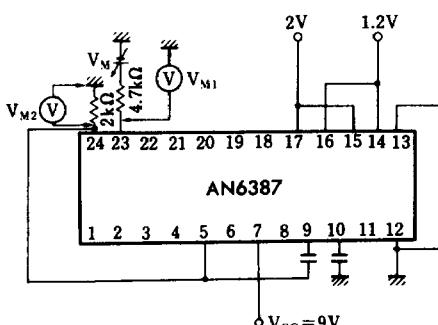
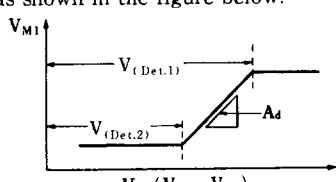
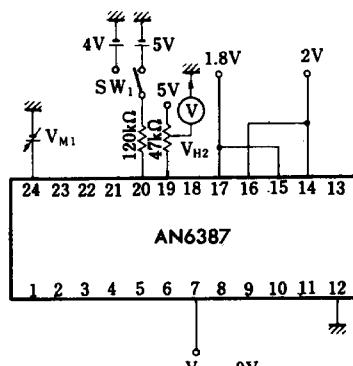
■ Absolute Maximum Ratings (Ta = 25°C)

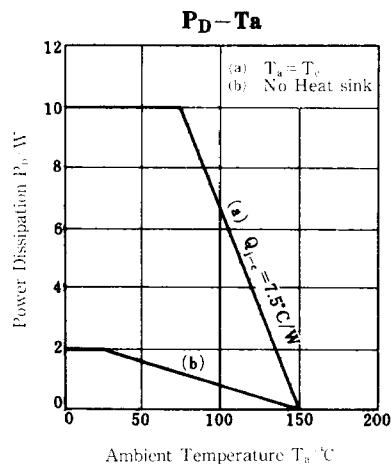
Item	Symbol	Rating		Unit	Note
Supply Voltage	V _{CC}	14.4		V	
Circuit Voltage	V _{n-12}	0	40	V	n=1,2,23
Circuit Voltage	V ₂₁₋₁₂	0	24	V	
Circuit Current	I _n	0	1500	mA	n=1,2,23
Power Dissipation	P _D	10		W	
Operating Ambient Temperature	V _{opr}	-20 ~ +70		°C	
Storage Temperature	T _{stg}	-40 ~ +150		°C	

■ Electrical Characteristics (Ta = 25°C ± 2°C)

Item	Symbol	Test Circuit	Condition	min.	typ.	max.	Unit
Total Current	I _{tot}	1	V _{CC} =9V, disable	4.0		20	mA
ET-ATC Transfer Gain	G _(TO)	2	V _{CC} =9V	0.86		1.06	
ATC Limit Voltage	V _(lim)	2	V _{CC} =9V, at full-torque command	0.44		0.50	V
Saturation Detect Gain	G _(S)	3	V _{CC} =9V, R _d =0.47Ω	0.5		1.5	
Saturation Detect Start Voltage	V _(Det 1)	3	V _{CC} =9V, R _d =0.47Ω	1.0		1.8	V
Saturation Detect End Voltage	V _(Det 2)	3	V _{CC} =9V, R _d =0.47Ω	0.5		1.0	V
HV Output Voltage	V _{HV}	1	V _{CC} =9V, V _{SV} =2.6V, R _{HV} =270Ω	2.1			V
HV Protect Voltage	V _(Protect)	1	V _{CC} =9V, V _{SV} =V _{CC}	3.5		4.3	V
DS Level Voltage	V _{DS}	2	V _{CC} =9V			1.2	V
ETR Voltage	V _{ETR}	2	V _{CC} =9V	4.3		4.7	V
HEM, HEM, HES, HES Bias Current	I _{Bias}	2	V _{CC} =9V	-6			μA
HES-HES Comparator Offset Voltage	V _{(offset)HES}	2	V _{CC} =9V	-6		6	mV
HEM-HEM Comparator Offset Voltage	V _{(offset)HM}	2	V _{CC} =9V	-6		6	mV
PG Lowest Voltage	V _{OL19}	2	V _{CC} =9V, 47kΩ applied to Pin⑯→5V			0.5	V
FG Lowest Voltage	V _{OL29}	4	V _{CC} =9V, 47kΩ applied to Pin⑰→5V			0.5	V
BEF Fetch Voltage	V _{BFG}	4	V _{CC} =V _M =9V	0.6		1.0	V

Note: Operating Supply Voltage Range : V_{CC(opr)}=8~13V (V₇₋₁₂)

Test Circuit 1 (I_{tot}, V_{HV}, V_(Protect))SW₁: Open, Current Value I_{CC}SW₁: Open, Pin ③ Voltage 2.6V...Pin④ Voltage V_{HV}SW₁: Short, Pin ④ Voltage...V_(Protect)**Test Circuit 2 (G_(IO), V_(lim), V_{DS}, V_{ETR}, I_{Bias}, V_{I(offset)S}, V_{I(offset)M}, V_{OL19})**Read V_{M1} and V_{M2} when V_{HES}=V_{HEM}=2V, V_{DS}=2V and V_S=0~6V.G_{IO}, V_(lim)(V_{HES}, V_{HEM}, V_{HE} current...I_{Bias})Read V_{M1} when V_S=0V. ...V_{ETR}V_{HES}=V_{HEM}=2V, V_{DS}=2VContinuously lowering V_{HES} from 2V, the voltage of V_{HES}-V_{HE} when V_{M3} went down : V_{I(offset)S}
Next, continuously lowering V_{HEM} from 2V, the voltage of V_{HEM}-V_{HE} when V_{M3} went down : V_{I(offset)M}, and lowest voltage of V_{M3}...V_{OL19}**Test Circuit 3 (G_(S), V_(Det.1), V_(Det.2))**Set V_M at 2V. Continuously increase V_M until it is as shown in the figure below.**Test Circuit 4 (V_{OL20}, V_{BFG})**When S₁=5V and V_{M1}=9V, V_{M2}...High voltage
When S₁=4V and V_{M1}=9V, V_{M2}...Low voltage...V_{OL20}. At this time, continuously increase V_{M1} up to 10V.Next, when V_{M1} continuously lowering for S₁=5V, the voltage of V_{M1} when V_{M2} became High voltage ...V_{BS}.



■ Application Circuit

